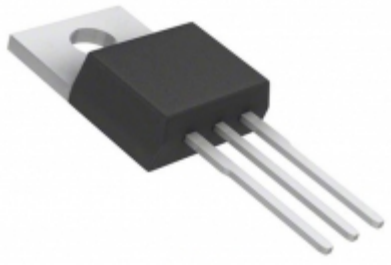

	<h2 style="color: red;">FQP13N10</h2>
	<p><b>Hersteller-Teilenummer:</b> FQP13N10</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 12.8A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP13N10.pdf</a> <a href="#">2.FQP13N10.pdf</a></p> <p><b>RoHS Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 78502 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQP13N10
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12.8A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	78502 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12.8A (Tc)
Rds On (Max) @ Id, Vgs	180 mOhm @ 6.4A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	450pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube

FQP13N10 ist neu im Original, Suche FQP13N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N10 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQP13N10: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FQP13N06</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13A TO-220</p>	 <p><b>FQP13N06L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>	 <p><b>FQP13N10</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p><b>FQP13N10C</b> FSC FQP13N10C FSC</p>
 <p><b>FQP13N06L</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>	 <p><b>FQP13N06</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 13A TO-220</p>	 <p><b>FQP13N06L FQP13N06</b> Original FQP13N06L FQP13N06 Original</p>	 <p><b>FQP13N10L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>

### heiße Teile

Mehr

⊗ FQP10N80	↔ FQP11N40C	⇒ FQP11N40C	D FQP11N50CF	⇒ FQP11N50CF
⊣ FQP11N60	⊗ FQP11N60C	D FQP11N65C	⇒ FQP11P06	⇒ FQP11P06
⊗ FQP12N20	⊣ FQP12N60	⊗ FQP12N60	↔ FQP12N60C	⇒ FQP12N60C
D FQP12N65C	⊗ FQP12P10	⊣ FQP12P10	⊗ FQP12P20	⇒ FQP12P20
⇒ FQP13N06	↔ FQP13N06	⊗ FQP13N06L	⊣ FQP13N06L	⇒ FQP13N10
↔ FQP13N10L	⇒ FQP13N10L	D FQP13N50	⊗ FQP13N50	⊣ FQP13N50C
⊗ FQP13N50C	D FQP13N60C	⇒ FQP140N03	↔ FQP140N03L	⇒ FQP14N15
⊣ FQP14N15	⊗ FQP14N30	↔ FQP14N30	⇒ FQP14N80	⇒ FQP14N80C
⊗ FQP15N16	⊣ FQP15N30	⊗ FQP15N50	D FQP15N60	⇒ FQP15N65
↔ FQP15N80	⊗ FQP15P12	⊣ FQP15P12	⊗ FQP16N15	⇒ FQP16N15

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited